

# TVS Diodes

Transient Voltage Suppression Diodes

ASMB Series



TVS

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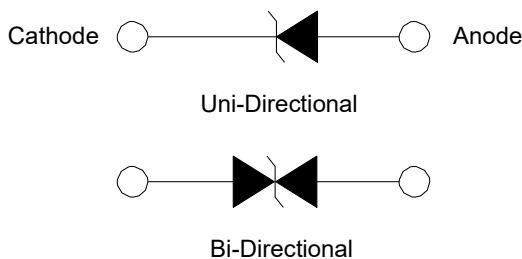
## Description

Transient Voltage Suppressor (TVS) is a circuit protection component that either attenuates (reduces) or filters a transient voltage spike (overvoltage), TVS diodes provide critical protection by going into avalanche breakdown within no more than a few nanoseconds after a strike, clamping the transient voltage, and routing its current to the ground.

## Applications

- Communication Equipment
- Security & Protection
- Industrial Control Equipment
- Power Supply
- Automotive Electronics
- New Energy
- Lightning Protection

## Functional Diagram



## Features

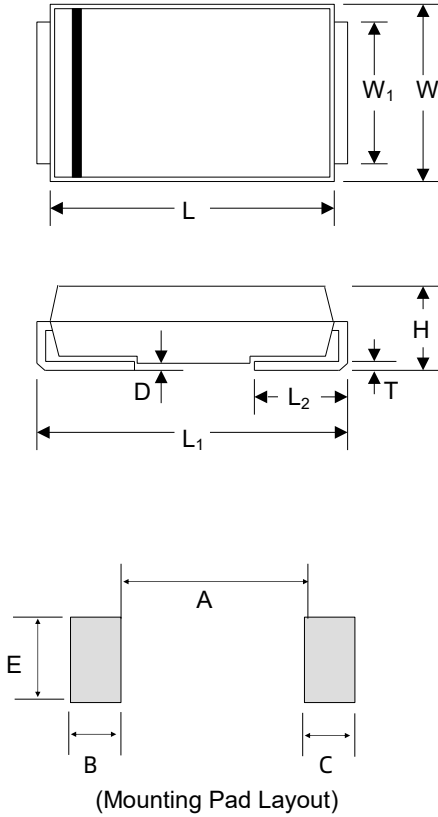
- Meet AEC-Q101 requirement
- Low incremental surge resistance
- Excellent clamping capability
- Low profile package with built-in strain relief
- Typical  $I_R$  less than 1.0  $\mu A$  above 12 V
- 600 W peak pulse power capability with a 10/1000  $\mu S$  Waveform, repetition rate (duty cycle): 0.01%
- For surface mounted applications to optimize board space
- Typical failure mode is short from over-specified voltage or current
- IEC 61000-4-2 ESD 30 kV (Air), 30 kV (Contact)
- EFT protection of data lines in accordance with IEC 61000-4-4
- Very fast response time
- Glass passivated chip junction
- High temperature to reflow soldering guaranteed: 260  $^{\circ}C/30sec$
- $V_{BR} @ T_J = V_{BR@25^{\circ}C} \times (1 + \alpha T \times (T_J - 25))$   
( $\alpha T$ : Temperature Coefficient, typical value is 0.1%)
- Plastic package is flammability rated V-0 per Underwriters Laboratories
- Meet MSL level1, per J-STD-020
- Matte tin lead-free plated
- Halogen free and RoHS compliant
- Pb-free E3 means 2nd level interconnect is Pb-free and the terminal finish material is tin(Sn) (IPC/JEDEC J-STD-609A.01)

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## Package Outline Dimensions (DO-214AA)



Symbol	Millimeters		Inches	
	Min.	Max.	Min.	Max.
L	4.06	4.75	0.160	0.187
W	3.30	3.94	0.130	0.155
W <sub>1</sub>	1.93	2.20	0.076	0.086
H	1.99	2.61	0.078	0.103
T	0.152	0.305	0.0086	0.012
L <sub>1</sub>	5.21	5.59	0.205	0.220
L <sub>2</sub>	0.76	1.52	0.030	0.060
D	-	0.203	-	0.008
A	-	2.74	-	0.107
B	2.16	-	0.085	-
C	2.16	-	0.085	-
E	2.26	-	0.089	-

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## Maximum Ratings and Characteristics

(Ratings at 25 °C ambient temperature unless otherwise specified.)

Parameter	Symbol	Value	Unit
Peak Power Dissipation (Fig2) with a 10/1000 $\mu$ S waveform <sup>(1)(2)</sup> (Fig4)-Signal Die Parts	P <sub>PPM</sub>	600	W
Peak Power Dissipation (Fig2) with a 10/1000 $\mu$ S waveform <sup>(1)(2)</sup> (Fig.4)-Stacked Die Parts <sup>(5)</sup>	P <sub>PPM</sub>	800	W
Peak Power Dissipation on Infinite Heat Sink at T <sub>L</sub> =50 °C	P <sub>D</sub>	5.0	W
Peak Forward Surge Current, 8.3 ms single half sinewave superimposed on rated load (JEDEC Method) <sup>(3)</sup>	I <sub>FSM</sub>	100	A
Maximum Instantaneous Forward Voltage at 50 A for Unidirectional Only <sup>(4)</sup>	V <sub>F</sub>	3.5/5.0	V
Operating Temperature Range	T <sub>J</sub>	-65 to 150	°C
Storage Temperature Range	T <sub>STG</sub>	-65 to 175	°C
Typical Thermal Resistance Junction to Lead	R <sub>θJL</sub>	20	°C / W
Typical Thermal Resistance Junction to Ambient	R <sub>θJA</sub>	100	°C / W

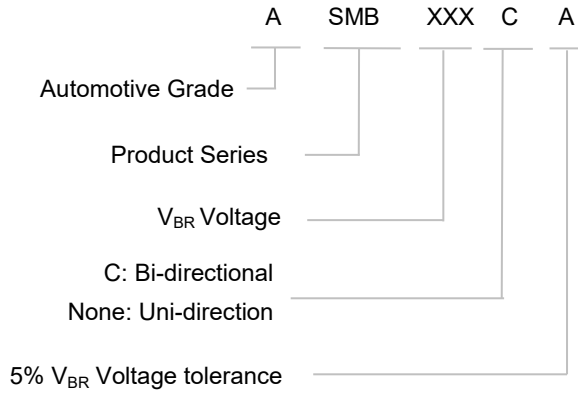
### Notes

1. Non-repetitive current pulse, per Fig. 4 and derated above T<sub>J</sub>(initial)=25 °C per Fig. 3.
2. Mounted on 5.0 mm<sup>2</sup> land areas.
3. Measured of 8.3 ms single half sine-wave or equivalent square wave, duty cycle=4 pulses per minute maximum.
4. V<sub>F</sub> < 3.5 V for single die parts and V<sub>F</sub> < 5.0 V for stacked-die parts.
5. For stacked die component details, please refer to part numbers labeled by \* in Electrical Characteristics.

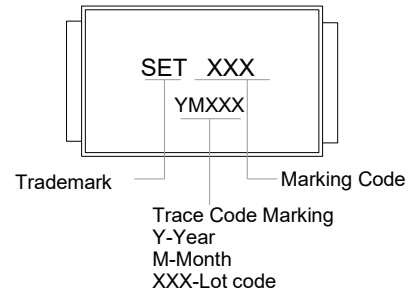
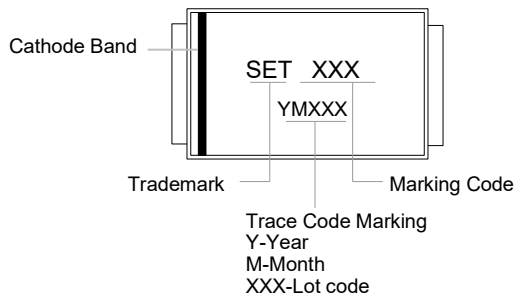
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## Part Numbering System



## Marking



## Glossary

Item	Description
$V_C$	<b>Clamping Voltage</b> Voltage across TVS in a region of low differential resistance that serves to limit the voltage across the device terminals.
$V_R$	<b>Reverse Stand-off Voltage</b> Maximum voltage that can be applied to the TVS without operation. NOTE : It is also shown as $V_{WM}$ (maximum working voltage (maximum d.c. voltage)) and known as rated stand-off voltage ( $V_{so}$ ).
$I_R$	<b>Reverse Leakage Current</b> Current measured at $V_R$ . NOTE : Also shown as $I_D$ for stand-by current.
$V_{BR}$	<b>Breakdown Voltage</b> Voltage across TVS at a specified current $I_T$ in the breakdown region.
$I_{PPM}$	<b>Rated Random Recurring Peak Impulse Current</b> Maximum-rated value of random recurring peak impulse current that may be applied to a device.
$P_{M(AV)}$	<b>Rated Average Power Dissipation</b> Maximum-rated value of power dissipation resulting from all sources, including transients and standby current, averaged over a short period of time.
$P_{PPM}$	<b>Rated Random Recurring Peak Impulse Power Dissipation</b> Maximum-rated value of the product of rated random recurring peak impulse current ( $I_{PPM}$ ) multiplies by specified maximum clamping voltage ( $V_C$ ).
$C_J$	<b>Capacitance</b> Capacitance across the TVS measured at a specified frequency and voltage.
$V_{FS}$	<b>Peak Forward Surge Voltage</b> Peak voltage across an TVS for a specified forward surge current ( $I_{FS}$ ) and time duration. NOTE : Also shown as $V_F$ .
$I_{FS}$	<b>Forward Surge Current</b> Pulsed current through TVS in the forward conducting region. NOTE : Also shown as $I_F$ .
$\alpha_{V(BR)}$	<b>Temperature Coefficient of Breakdown Voltage</b> The change of breakdown voltage divided by the change of temperature.
$I_{PP}$	<b>Peak pulse Current</b> Peak pulse current value applied across the TVS to determine the clamping voltage $V_C$ for a specified wave shape.
$I_T$	<b>Pulsed D.C. Test Current</b> Test current for measurement of the breakdown voltage $V_{BR}$ . This is defined by the manufacturer and usually given in milliamperes with a pulse duration of less than 40 ms. NOTE : Also shown as $I_{BR}$ .

—(GB-T 18802.321 / IEC 61643-321 / JESD210A)

**Electrical Characteristics** ( $T_A=25^{\circ}\text{C}$  unless otherwise noted )Table 1

Part Number		Device Marking Code		Breakdown Voltage $V_{BR}@I_T$		Test Current $I_T$	Reverse Stand-off Voltage $V_R$	Max. Reverse Leakage $I_R@V_R$	Max. Peak Pulse Current $I_{PPM}$	Max. Clamping Voltage $V_C@I_{PPM}$
Uni	Bi	Uni	Bi	Min	Max					
Uni	Bi	Uni	Bi	(V)		(mA)	(V)	( $\mu\text{A}$ )	(A)	(V)
ASMB6.8A	ASMB6.8CA	A6V8A	A6V8C	6.45	7.14	10	5.8	1000	58.1	10.5
ASMB7.5A	ASMB7.5CA	A7V5A	A7V5C	7.13	7.88	10	6.4	500	54	11.3
ASMB8.2A	ASMB8.2CA	A8V2A	A8V2C	7.79	8.61	10	7.02	200	50.4	12.1
ASMB9.1A	ASMB9.1CA	A9V1A	A9V1C	8.65	9.55	1	7.78	50	45.5	13.4
ASMB10A	ASMB10CA	A10A	A10C	9.5	10.5	1	8.55	10	42.1	14.5
ASMB11A	ASMB11CA	A11A	A11C	10.5	11.6	1	9.4	5	39.1	15.6
ASMB12A	ASMB12CA	A12A	A12C	11.4	12.6	1	10.2	5	36.5	16.7
ASMB13A	ASMB13CA	A13A	A13C	12.4	13.7	1	11.1	1	33.5	18.2
ASMB15A	ASMB15CA	A15A	A15C	14.3	15.8	1	12.8	1	28.8	21.2
ASMB16A	ASMB16CA	A16A	A16C	15.2	16.8	1	13.6	1	27.1	22.5
ASMB18A	ASMB18CA	A18A	A18C	17.1	18.9	1	15.3	1	24.2	25.5
ASMB20A	ASMB20CA	A20A	A20C	19	21	1	17.1	1	22	27.7
ASMB22A	ASMB22CA	A22A	A22C	20.9	23.1	1	18.8	1	19.9	30.6
ASMB24A	ASMB24CA	A24A	A24C	22.8	25.2	1	20.5	1	18.4	33.2
ASMB27A	ASMB27CA	A27A	A27C	25.7	28.4	1	23.1	1	16.3	37.5
ASMB30A	ASMB30CA	A30A	A30C	28.5	31.5	1	25.6	1	14.7	41.4
ASMB33A	ASMB33CA	A33A	A33C	31.4	34.7	1	28.2	1	13.3	45.7
ASMB36A	ASMB36CA	A36A	A36C	34.2	37.8	1	30.8	1	12.2	49.9
ASMB39A	ASMB39CA	A39A	A39C	37.1	41	1	33.3	1	11.3	53.9
ASMB43A	ASMB43CA	A43A	A43C	40.9	45.2	1	36.8	1	10.3	59.3
ASMB47A	ASMB47CA	A47A	A47C	44.7	49.4	1	40.2	1	9.4	64.8
ASMB51A	ASMB51CA	A51A	A51C	48.5	53.6	1	43.6	1	8.7	70.1
ASMB56A	ASMB56CA	A56A	A56C	53.2	58.8	1	47.8	1	7.9	77

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Part Number		Device Marking Code		Breakdown Voltage $V_{BR}@I_T$		Test Current $I_T$	Reverse Stand-off Voltage $V_R$	Max. Reverse Leakage $I_R@V_R$	Max. Peak Pulse Current $I_{PPM}$	Max. Clamping Voltage $V_C@I_{PPM}$
				Min	Max					
Uni	Bi	Uni	Bi	(V)		(mA)	(V)	( $\mu$ A)	(A)	(V)
ASMB58A	ASMB58CA	A58A	A58C	55.1	60.9	1	52.78	1	7.7	79.8
ASMB62A	ASMB62CA	A62A	A62C	58.9	65.1	1	53	1	7.2	85
ASMB68A	ASMB68CA	A68A	A68C	64.6	71.4	1	58.1	1	6.6	92
ASMB75A	ASMB75CA	A75A	A75C	71.3	78.8	1	64.1	1	5.9	103
ASMB82A	ASMB82CA	A82A	A82C	77.9	86.1	1	70.1	1	5.4	113
ASMB91A	ASMB91CA	A91A	A91C	86.5	95.5	1	77.8	1	4.9	125
ASMB100A	ASMB100CA	A100A	A100C	95	105	1	85.5	1	4.5	137
ASMB110A	ASMB110CA	A110A	A110C	105	116	1	94	1	4	152
ASMB120A	ASMB120CA	A120A	A120C	114	126	1	102	1	3.7	165
ASMB130A	ASMB130CA	A130A	A130C	124	137	1	111	1	3.4	179
ASMB150A	ASMB150CA	A150A	A150C	143	158	1	128	1	2.9	207
ASMB160A	ASMB160CA	A160A	A160C	152	168	1	136	1	2.8	219
ASMB170A	ASMB170CA	A170A	A170C	162	179	1	145	1	2.6	234
ASMB180A	ASMB180CA	A180A	A180C	171	189	1	154	1	2.5	246
ASMB200A	ASMB200CA	A200A	A200C	190	210	1	171	1	2.2	274
ASMB220A	ASMB220CA	A220A	A220C	209	231	1	185	1	1.9	328
ASMB250A	ASMB250CA	A250A	A250C	237	263	1	214	1	1.8	344
ASMB300A	ASMB300CA	A300A	A300C	285	315	1	256	1	1.5	414
ASMB350A*	ASMB350CA*	A350A	A350C	332	368	1	300	1	1.3	482
ASMB400A*	ASMB400CA*	A400A	A400C	380	420	1	342	1	1.1	548
ASMB440A*	ASMB440CA*	A440A	A440C	418	462	1	376	1	1.0	602
ASMB480A*	ASMB480CA*	A480A	A480C	456	504	1	408	1	0.9	658
ASMB510A*	ASMB510CA*	A510A	A510C	485	535	1	434	1	0.9	698
ASMB520A*	ASMB520CA*	A520A	A520C	494.5	545.5	1	443	1	0.9	718
ASMB530A*	ASMB530CA*	A530A	A530C	503.5	556.5	1	451	1	0.8	725
ASMB540A*	ASMB540CA*	A540A	A540C	513	567	1	460	1	0.8	740
ASMB550A*	ASMB550CA*	A550A	A550C	522.5	577.5	1	468	1	0.8	760
ASMB600A*	ASMB600CA*	A600A	A600C	570	630	1	512	1	0.8	828
ASMB650A*	ASMB650CA*	A650A	A650C	617.5	682.5	1	553	1	0.8	897

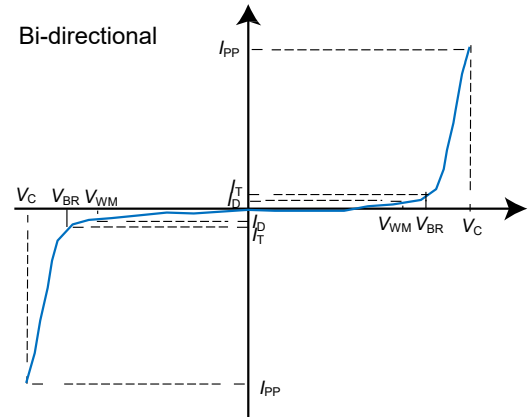
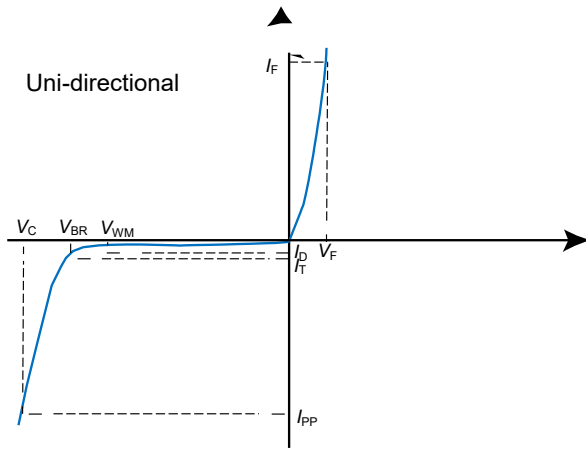
Notes:

1. For bidirectional type having  $V_R$  of 10 volts and less, the  $I_R$  should be doubled.
2. For parts without A in the PN, the  $V_{BR}$  tolerance is  $\pm 10\%$  and  $V_C$  is 5% higher than parts with A. The parts without A are currently available, but not recommended for new designs. The parts with A are preferred.
3. For stacked die component details, please refer to models marked with \* in electrical characteristics table.

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## I-V Curve Characteristics



## Performance Curve for Reference ( $T_A=25^\circ\text{C}$ unless otherwise noted)

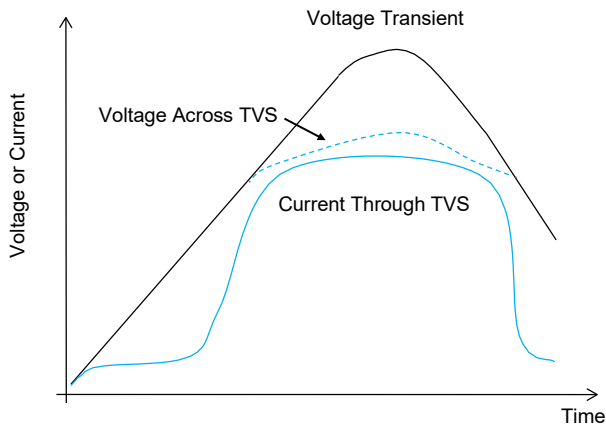


FIGURE 1 TVS Transients Clamping Waveform

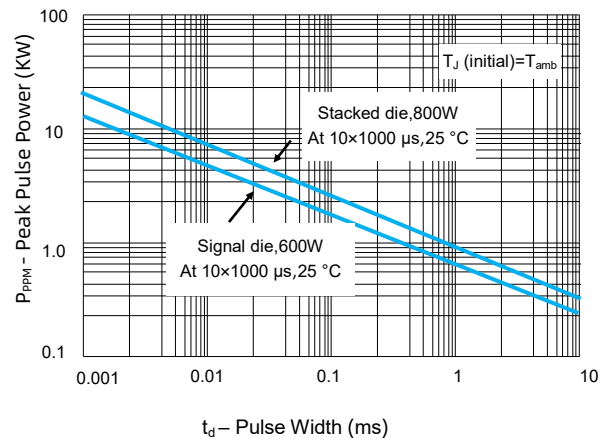


FIGURE 2 Peak Pulse Power Rating Curve

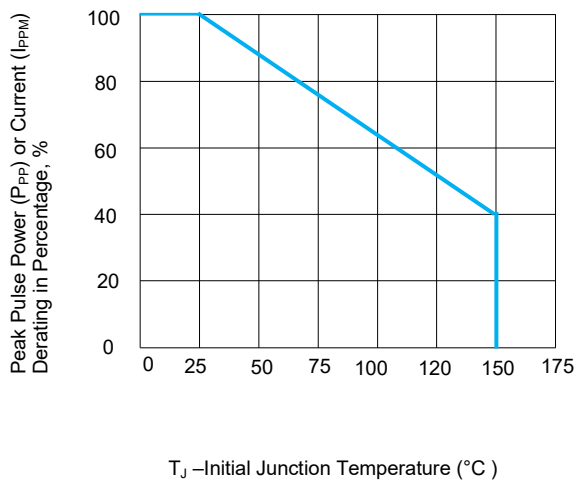


FIGURE 3 Peak Pulse Power Derating Curve

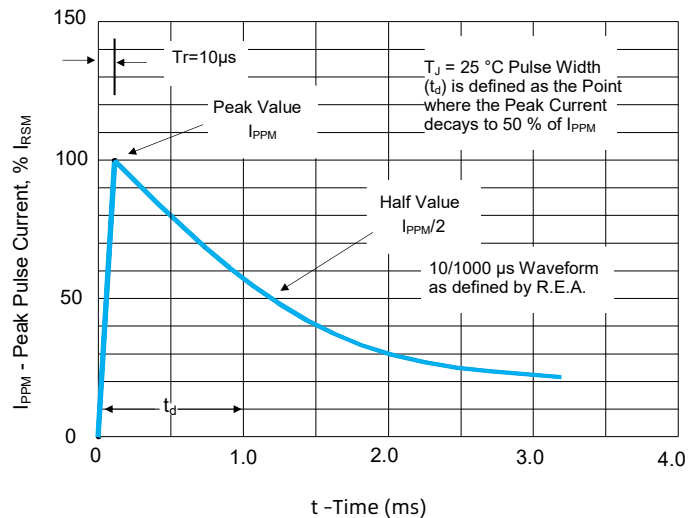


FIGURE 4 Pulse Waveform



# TVS Diodes

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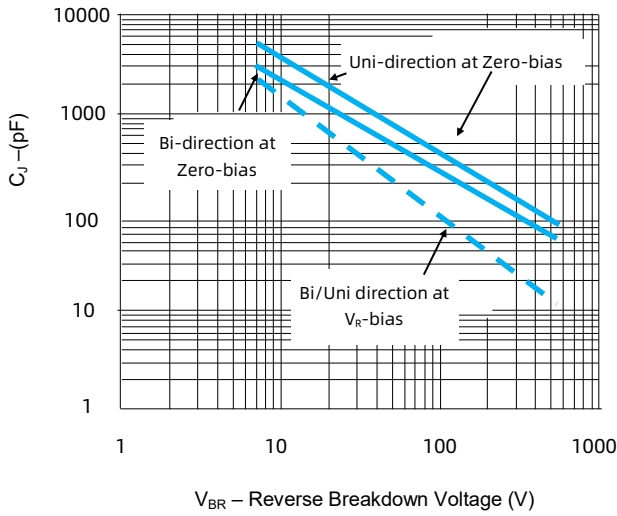


FIGURE 5 Typical Junction Capacitance

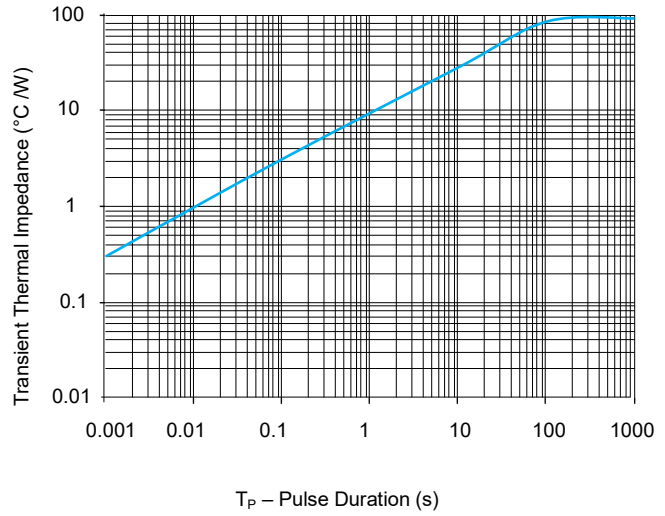


FIGURE 6 Typical Transient Thermal Impedance

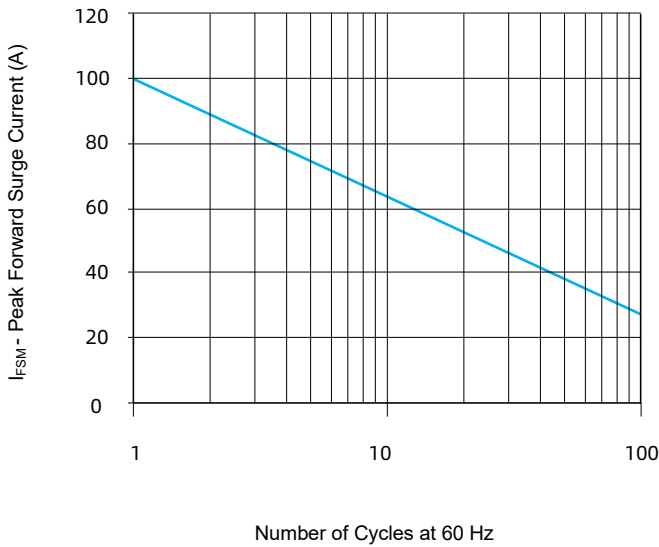


FIGURE 7 Maximum Non-Repetitive Forward Surge Current Uni-Directional only

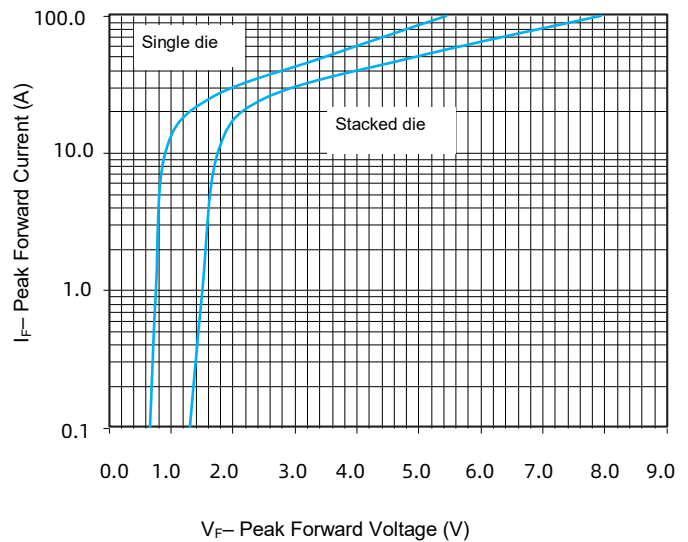


FIGURE 8 Peak Forward Drop vs Peak Forward Current (Typical Values)

## Environmental Specifications

High Temp. Storage	JESD22-A103
HTRB	JESD22-A108
Temperature Cycling	JESD22-A104
MSL	JESDEC-J-STD-020, Level 1
H3TRB	JESD22-A101
RSH	JESD22-A111

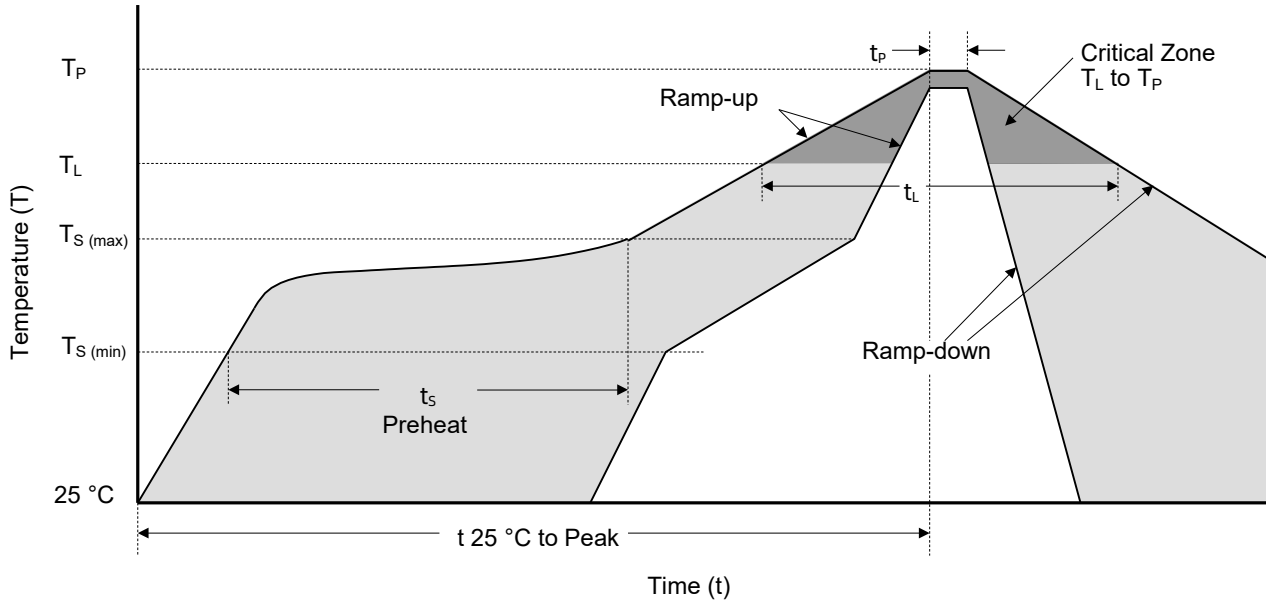
## Physical Specifications

Weight	0.003 ounce, 0.093 grams
Case	JESD22DO214AA. Molded plastic body over glass passivated junction
Polarity	Color band denotes positive end (cathode) except Bidirectional
Terminal	Matte Tin-plated leads, Solderability per JESD22-B102

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## Soldering Parameters



Reflowing Condition

Reflow Soldering Parameters		Lead-Free Assembly
Pre-heat	Temperature Min ( $T_{S (min)}$ )	150 °C
	Temperature Max ( $T_{S (max)}$ )	200 °C
	Time (min to max) ( $t_s$ )	60 ~ 120 seconds
Average Ramp Up Rate (Liquidus Temp ( $T_L$ ) to Peak)		3 °C / second max.
$T_{S (max)}$ to $T_L$ Ramp-up Rate		3 °C / second max.
Reflow	Temperature ( $T_L$ ) (Liquidus)	217 °C
	Time (min to max) ( $t_L$ )	60 ~ 150 seconds
Peak Temperature ( $T_P$ )		260 <sup>+0/-5</sup> °C
Time of within 5 °C of Actual Peak Temperature ( $t_p$ )		20 ~ 40 seconds
Ramp-down Rate		6 °C / second max.
Time from 25 °C to Peak Temperature		8 Minutes max.
Do Not Exceed		260 °C

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## Packaging Information

Tape	Symbol	Dimension (mm)
	W	12.00+0.30/-0.10
	P <sub>0</sub>	4.00±0.10
	P <sub>1</sub>	8.00±0.10
	P <sub>2</sub>	2.00±0.05
	D <sub>0</sub>	1.55±0.05
	D <sub>1</sub>	1.55±0.05
	E	1.75±0.10
	F	5.50±0.05
	A <sub>0</sub>	3.78±0.10
	B <sub>0</sub>	5.65±0.15
	K <sub>0</sub>	2.70±0.10
	T	0.30±0.05

Reel Size	13" Reel	
	A	330 mm
	C	13.2 mm
	W <sub>1</sub>	12.5 mm

Part Number	Package	QTY (Reel)	Packaging Option	Packaging Specification
ASMBxxx-XX	DO-214AA	3000 PCS	Tape & Reel – 12 mm tape/13" reel	EIA STD RS-481



# ATTENTION

## Usage

1. TVS must be operated in the specified ambient temp.
2. Do not clean the TVS with strong polar solvent such as ketone, esters, benzene and halogenated hydrocarbon, to avoid damaging the encapsulating layer.
3. Please do not apply severe vibration, shock or pressure to TVS, to avoid element cracking.

## Replacement

1. If TVS is visually damaged, please replace it.
2. TVS is a non-repairable product. For safety sake, please use equivalent TVS for replacement.

## Storage

1. Storage Temp. Range: (-55 to 150) °C.
2. Do not store the TVS at the high temp., high humidity or corrosive gas environment, to avoid influencing the solder-ability of the lead wires. The product shall be used up within 1 year after receiving the goods.

## Environmental Conditions

1. TVS should not be exposed to the open air, nor direct sunshine.
2. TVS should avoid rain, water vapor or other condition of high temp. and high humidity.
3. TVS should avoid sand dust, salt mist, or other harmful gases.

## Max. Typical Capacitance of TVS

The typical capacitance of TVS is listed in the specifications. Designers may refer to it when designing TVS in High frequency circuit.

## Installation Mechanical Stress

1. Do not knock TVS when installing, to avoid mechanical damage.
2. Please do not apply severe vibration, shock or pressure to TVS, to avoid surface resin or element cracking.